



# THE DATASHEET OF DVR5V0W-7



## COMPLEX ARRAY FOR VOLTAGE REGULATORS

### Features

- Epitaxial Planar Die Construction
- Selectively Paired NPN Transistors & Zener Diodes for Series Pass Voltage Regulator Circuits
- Ideally Suited for Automated Assembly Processes
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

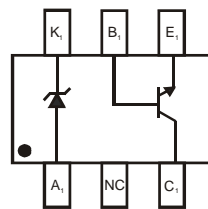
### Mechanical Data

- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Weight: 0.006 grams (Approximate)

SOT363



Top View



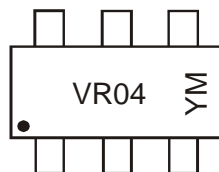
Top View  
Pin Configuration

### Ordering Information (Note 4)

| Device    | Packaging | Shipping         |
|-----------|-----------|------------------|
| DVR5V0W-7 | SOT363    | 3000/Tape & Reel |

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

### Marking Information



VR04 = Product Type Marking Code  
 YM = Date Code Marking  
 Y = Year ex: G = 2019  
 M = Month ex: 9 = September

#### Date Code Key

| Year | 2004 | 2005 | 2006 | 2007 | 2008 | ... | 2018 | 2019 | 2020 | 2021 | 2022 | 2023 |
|------|------|------|------|------|------|-----|------|------|------|------|------|------|
| Code | R    | S    | T    | U    | V    | ... | F    | G    | H    | I    | J    | K    |

| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
|-------|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|
| Code  | 1   | 2   | 3   | 4   | 5   | 6   | 7   | 8   | 9   | O   | N   | D   |

### Maximum Ratings, Total Device @T<sub>A</sub> = 25°C unless otherwise specified

| Characteristic                                   | Symbol                            | Value       | Unit |
|--|-----------------------------------|-------------|------|
| Power Dissipation (Note 5)                       | P <sub>d</sub>                    | 200         | mW   |
| Thermal Resistance, Junction to Ambient (Note 5) | R <sub>θJA</sub>                  | 625         | °C/W |
| Operating and Storage Temperature Range          | T <sub>j</sub> , T <sub>STG</sub> | -55 to +150 | °C   |

### Maximum Ratings, NPN Transistor @T<sub>A</sub> = 25°C unless otherwise specified

| Characteristic                                       | Symbol           | Value | Unit |
|--|------------------|-------|------|
| Collector-Base Voltage                               | V <sub>CB0</sub> | 45    | V    |
| Collector-Emitter Voltage                            | V <sub>CEO</sub> | 18    | V    |
| Emitter-Base Voltage                                 | V <sub>EBO</sub> | 5     | V    |
| Collector Current (with Forced Air Cooling) (Note 5) | I <sub>C</sub>   | 1     | A    |

### Maximum Ratings, Zener Element @T<sub>A</sub> = 25°C unless otherwise specified

| Characteristic                          | Symbol         | Value | Unit |
|---|----------------|-------|------|
| Forward Voltage @ I <sub>F</sub> = 10mA | V <sub>F</sub> | 0.9   | V    |

### Electrical Characteristics, NPN Transistor @T<sub>A</sub> = 25°C unless otherwise specified

| Characteristic                       | Symbol               | Min | Max | Unit | Test Condition   |
|--------------------------------------|----------------------|-----|-----|------|--|
| <b>OFF CHARACTERISTICS (Note 6)</b>  |                      |     |     |      |  |
| Collector-Base Breakdown Voltage     | V <sub>(BR)CBO</sub> | 45  | —   | V    | I <sub>C</sub> = 100μA, I <sub>E</sub> = 0               |
| Collector-Emitter Breakdown Voltage  | V <sub>(BR)CEO</sub> | 18  | —   | V    | I <sub>C</sub> = 1mA, I <sub>B</sub> = 0                 |
| Emitter-Base Breakdown Voltage       | V <sub>(BR)EBO</sub> | 5   | —   | V    | I <sub>E</sub> = 100μA, I <sub>C</sub> = 0               |
| Collector Cutoff Current             | I <sub>CB0</sub>     | —   | 1   | μA   | V <sub>CB</sub> = 40V, I <sub>E</sub> = 0                |
| Emitter Cutoff Current               | I <sub>EBO</sub>     | —   | 1   | μA   | V <sub>EB</sub> = 4V, I <sub>C</sub> = 0                 |
| <b>ON CHARACTERISTICS (Note 6)</b>   |                      |     |     |      |  |
| DC Current Gain                      | h <sub>FE</sub>      | 150 | 800 | —    | I <sub>C</sub> = 100mA, V <sub>CE</sub> = 1V             |
| Collector-Emitter Saturation Voltage | V <sub>CE(SAT)</sub> | —   | 0.5 | V    | I <sub>C</sub> = 300mA, I <sub>B</sub> = 30mA            |
| <b>SMALL SIGNAL CHARACTERISTICS</b>  |                      |     |     |      |  |
| Output Capacitance                   | C <sub>obo</sub>     | —   | 8   | pF   | V <sub>CB</sub> = 10V, f = 1.0MHz, I <sub>E</sub> = 0    |
| Current Gain-Bandwidth Product       | f <sub>T</sub>       | 100 | —   | MHz  | V <sub>CB</sub> = 10V, I <sub>E</sub> = 50mA, f = 100MHz |

### Electrical Characteristics, Zener Element @T<sub>A</sub> = 25°C unless otherwise specified

| Zener Voltage Range (Note 7)     |         |         |                 | Maximum Reverse Leakage Current (Note 6) |   |
|----------------------------------|---------|---------|-----------------|--|---|
| V <sub>Z</sub> @ I <sub>ZT</sub> |         |         | I <sub>ZT</sub> | I <sub>R</sub> @ V <sub>R</sub>          |   |
| Nom (V)                          | Min (V) | Max (V) | mA              | μA                                       | V |
| 5.1                              | 4.85    | 5.36    | 0.05            | 5  | 3 |

- Notes:
- Part mounted on FR-4 substrate PC board, with 1 inch square, 2oz copper pad layout.
  - Short duration pulse test used to minimize self-heating effect.
  - Nominal Zener voltage is measured with the device junction in thermal equilibrium at T<sub>T</sub> = 30°C ±1°C.

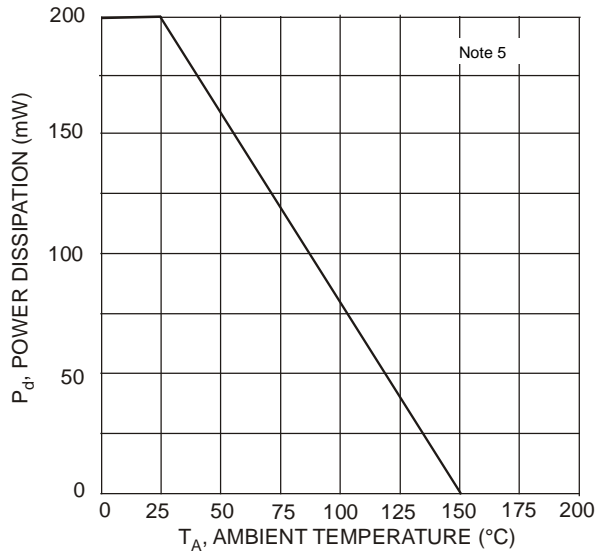


Fig. 1 Max Power Dissipation vs. Ambient Temperature (Total Device)

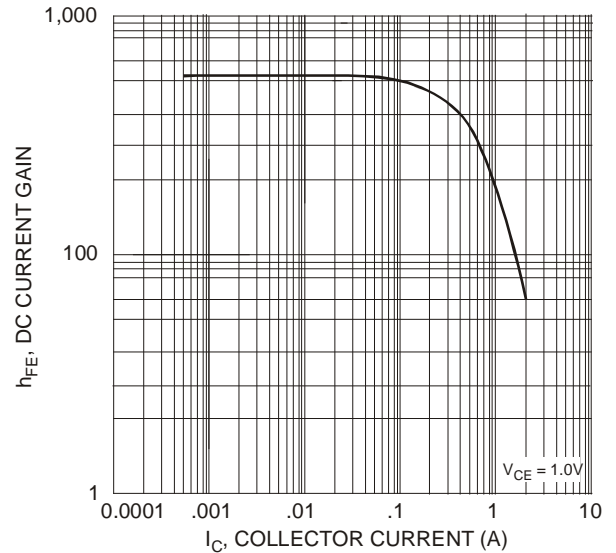


Fig. 2 Typical DC Current Gain vs. Collector Current (NPN Transistor)

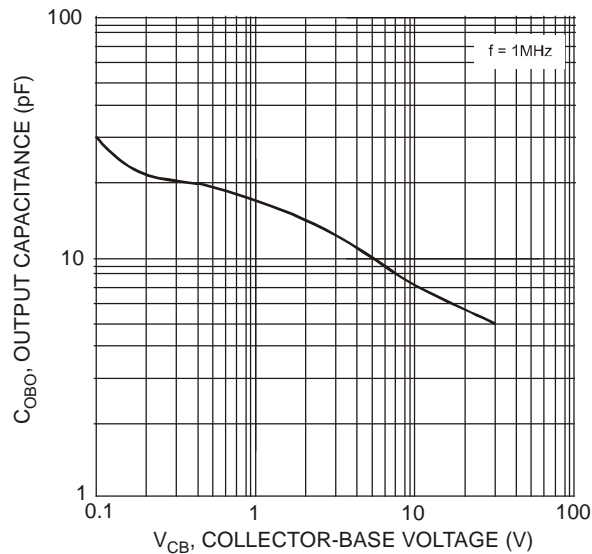


Fig. 3 Typical Output Capacitance vs. Collector-Base Voltage (NPN Transistor)

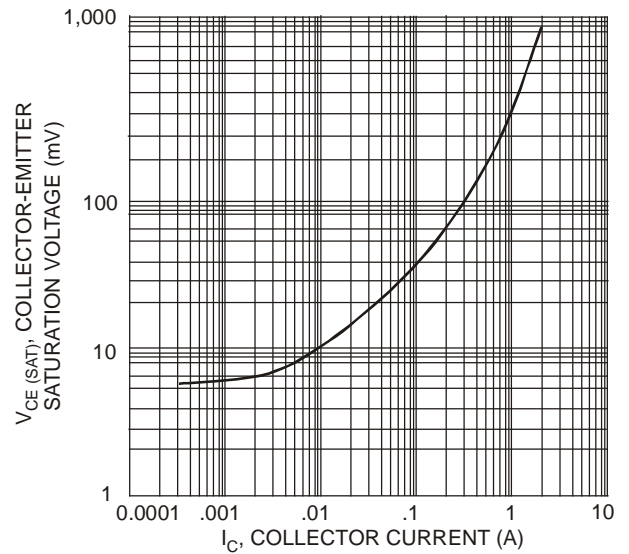


Fig. 4 Typical Collector Saturation Voltage vs. Collector Current (NPN Transistor)

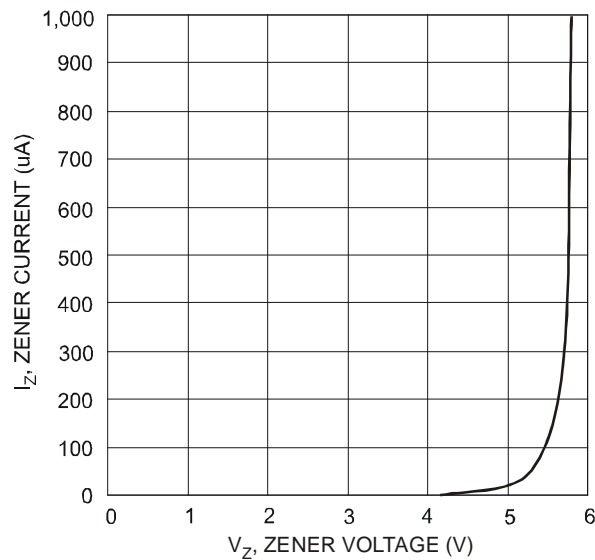
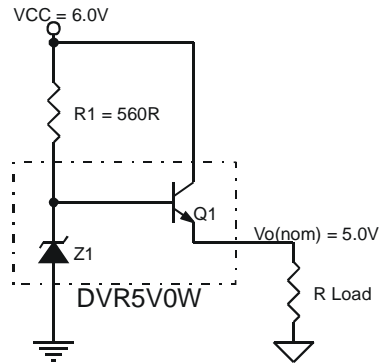


Fig. 5 Typical Zener Breakdown Characteristics

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## Sample Applications

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### Sample Application for DVR5V0W:

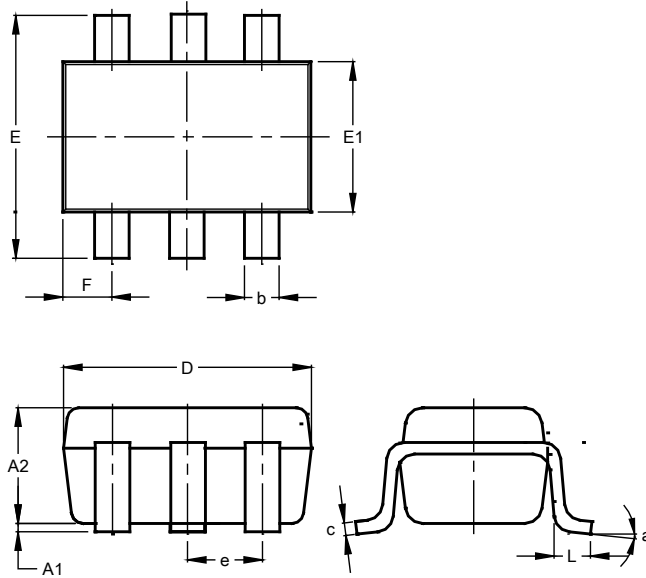
$V_{CC} = 6.0V$        $R1 = 560\Omega$   
 $V_o(\text{nom}) = 5.0V$        $I_o = 100\text{mA}$   
 $I_q(\text{typical}) = 0.5\text{mA} @ I_o = 0\text{mA}$   
Typical  $V_{\text{reg}}(\text{load}) = 0.2V$  from  $I_o = 100\text{mA}$  to  $0\text{mA}$

- Notes:
8. Resistor R1 not included.
  9. Typical performance shown is under setup and operating conditions specified in the sample applications.
  10. Recommended  $V_{CC}(\text{min}) = V_o(\text{nom}) + 1V$ .

## Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SOT363**

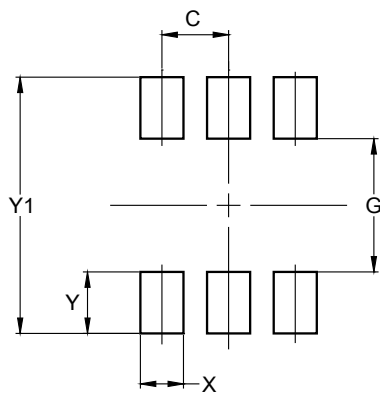


| SOT363               |           |      |       |
|----------------------|-----------|------|-------|
| Dim                  | Min       | Max  | Typ   |
| A1                   | 0.00      | 0.10 | 0.05  |
| A2                   | 0.90      | 1.00 | 0.95  |
| b                    | 0.10      | 0.30 | 0.25  |
| c                    | 0.10      | 0.22 | 0.11  |
| D                    | 1.80      | 2.20 | 2.15  |
| E                    | 2.00      | 2.20 | 2.10  |
| E1                   | 1.15      | 1.35 | 1.30  |
| e                    | 0.650 BSC |      |       |
| F                    | 0.40      | 0.45 | 0.425 |
| L                    | 0.25      | 0.40 | 0.30  |
| a                    | 0°        | 8°   | --    |
| All Dimensions in mm |           |      |       |

## Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SOT363**



| Dimensions | Value (in mm) |
|------------|---------------|
| C          | 0.650         |
| G          | 1.300         |
| X          | 0.420         |
| Y          | 0.600         |
| Y1         | 2.500         |

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